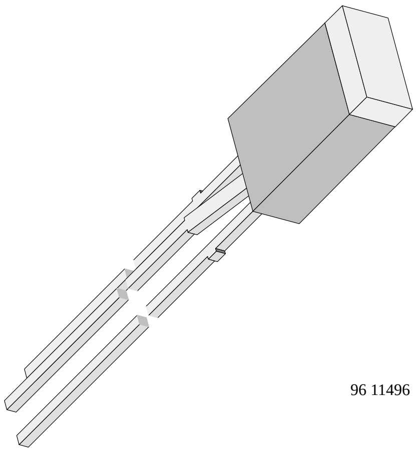
Bicolor Symbol LED, 2.5 x 5 mm Untinted Top Diffused

Color	Type	Technology	Angle of Half Intensity ±φ
High efficiency red	TLSV5100	GaAsP on GaP	50°
Green		GaP on GaP	

Features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- Even luminance of the emitting surface
- Ideal as flush mounted panel indicators
- For DC and pulse operation
- Color mixing possible due to separate anode terminals
- Luminous intensity selected into groups
- Categorized for green color
- Wide viewing angle
- Common cathode

Applications

Indicating and illumination purposes.

Absolute Maximum Ratings

T_{amb} = 25°C, unless otherwise specified

TLSV5100

Parameter	Test Conditions	Type	Symbol	Value	Unit
Reverse voltage per diode			V_R	6	V
DC forward current per diode			I_F	30	mA
Surge forward current per diode	$t_p \leq 10\ \mu s$		I_{FSM}	1	A
Power dissipation per diode	$T_{amb} \leq 55^\circ C$		P_V	100	mW
Total power dissipation	$T_{amb} \leq 55^\circ C$		P_{tot}	150	mW
Junction temperature			T_j	100	˚C
Storage temperature range			T_{stg}	–55 to +100	˚C
Soldering temperature	t ≤ 5 s, 2 mm from body		T_{sd}	260	˚C
Thermal resistance junction/ambient per diode			R_{thJA}	450	K/W
Thermal resistance junction/ambient total			R_{thJA}	300	K/W

Optical and Electrical Characteristics

T_{amb} = 25°C, unless otherwise specified

High efficiency red (TLSV5100)

Parameter	Test Conditions	Type	Symbol	Min	Typ	Max	Unit
Per diode							
Luminous intensity	I_F = 10 mA, $I_{Vmin}/I_{Vmax} \geq 0.5$		I_V	0.63	1		mcd
Dominant wavelength	I_F = 10 mA		λ_d	612		625	nm
Peak wavelength	I_F = 10 mA		λ_p		635		nm
Angle of half intensity	I_F = 10 mA		φ		±50		deg
Forward voltage	I_F = 20 mA		V_F		2	3	V
Reverse voltage	I_R = 10 μA		V_R	6	15		V
Junction capacitance	V_R = 0, f = 1 MHz		C_j		50		pF

Green (TLSV5100)

Parameter	Test Conditions	Type	Symbol	Min	Typ	Max	Unit
Per diode							
Luminous intensity	I_F = 10 mA, $I_{Vmin}/I_{Vmax} \geq 0.5$		I_V	0.63	1		mcd
Dominant wavelength	I_F = 10 mA		λ_d	562		575	nm
Peak wavelength	I_F = 10 mA		λ_p		565		nm
Angle of half intensity	I_F = 10 mA		φ		±50		deg
Forward voltage	I_F = 20 mA		V_F		2.4	3	V
Reverse voltage	I_R = 10 μA		V_R	6	15		V
Junction capacitance	V_R = 0, f = 1 MHz		C_j		50		pF

Typical Characteristics (T$_{amb}$ = 25°C, unless otherwise specified)

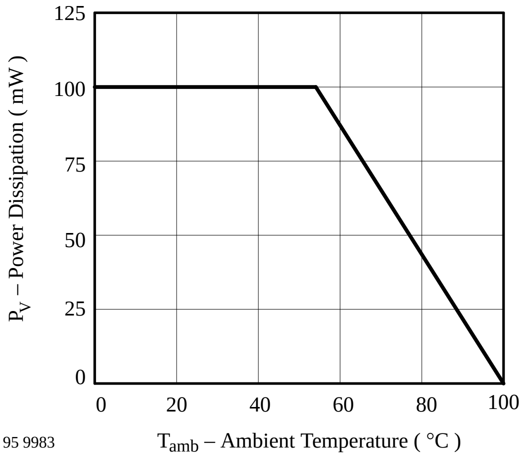


Figure 1. Power Dissipation vs. Ambient Temperature

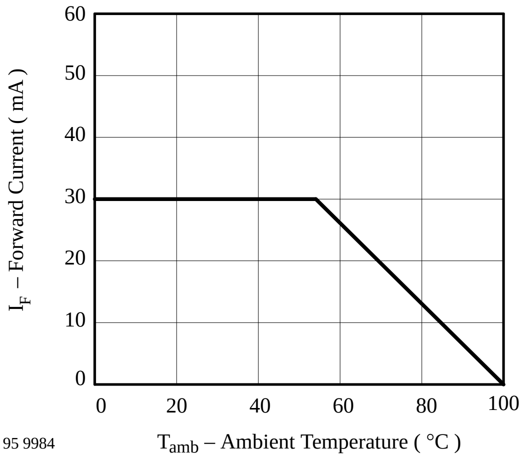


Figure 2. Forward Current vs. Ambient Temperature

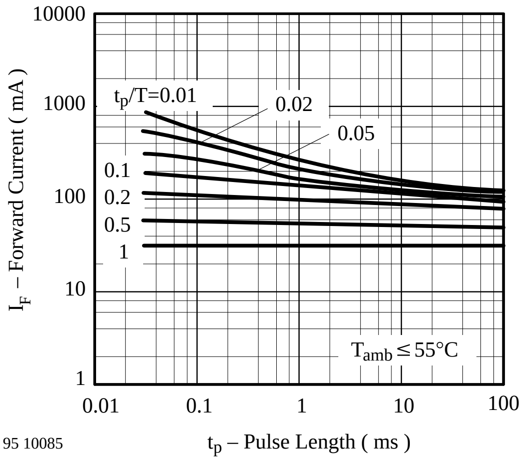


Figure 3. Forward Current vs. Pulse Length

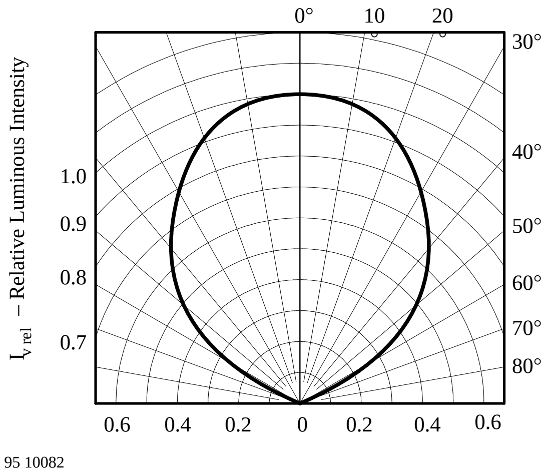


Figure 4. Rel. Luminous Intensity vs. Angular Displacement

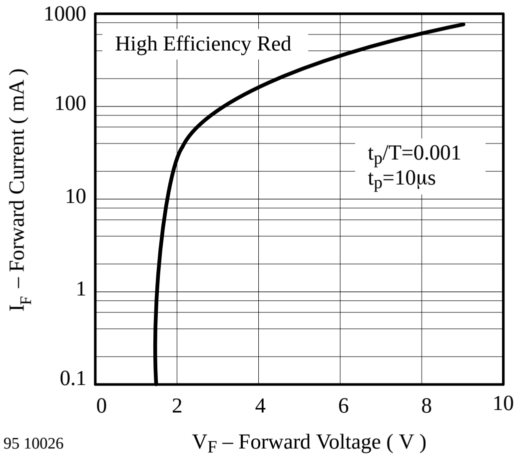


Figure 5. Forward Current vs. Forward Voltage

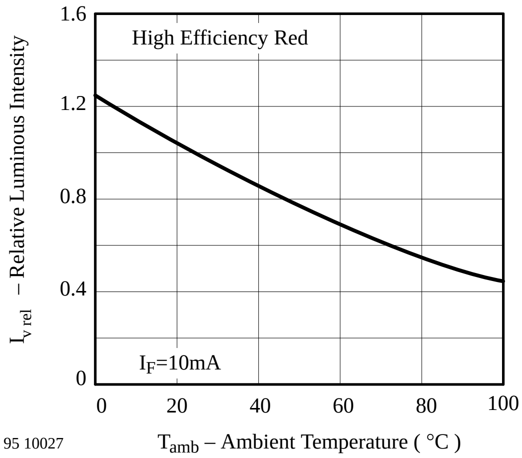


Figure 6. Rel. Luminous Intensity vs. Ambient Temperature

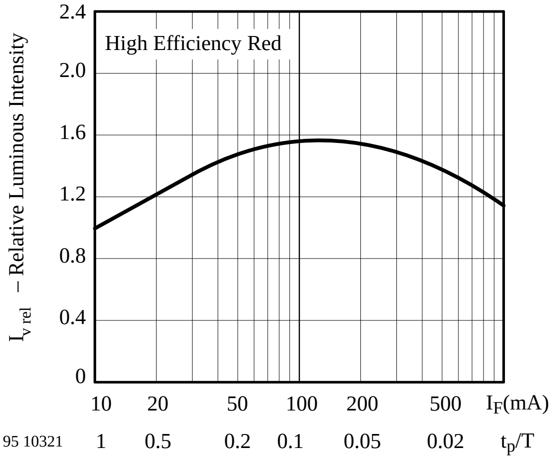


Figure 7. Rel. Lumin. Intensity vs. Forw. Current/Duty Cycle

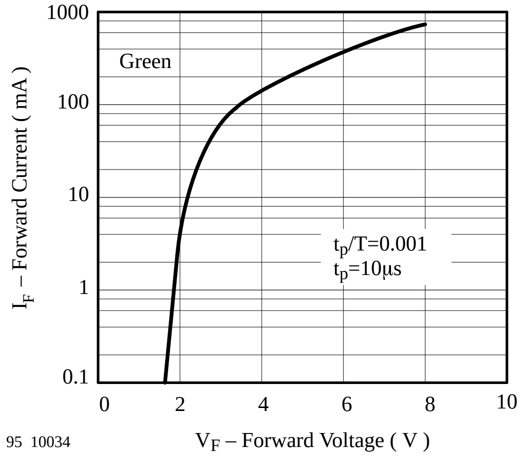


Figure 10. Forward Current vs. Forward Voltage

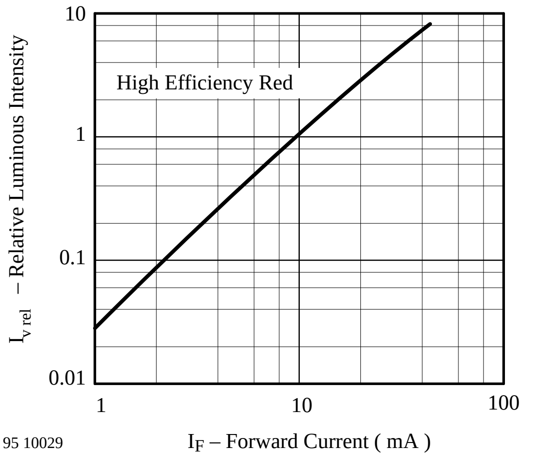


Figure 8. Relative Luminous Intensity vs. Forward Current

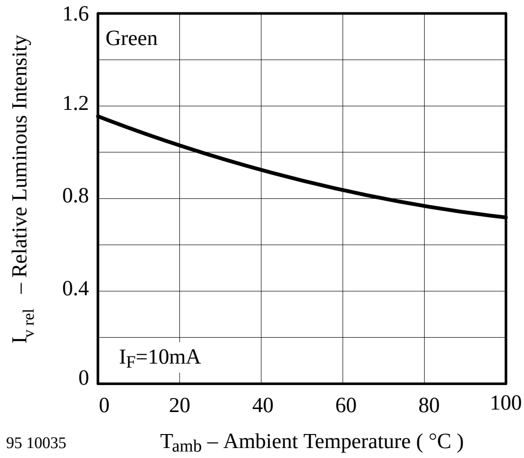


Figure 11. Rel. Luminous Intensity vs. Ambient Temperature

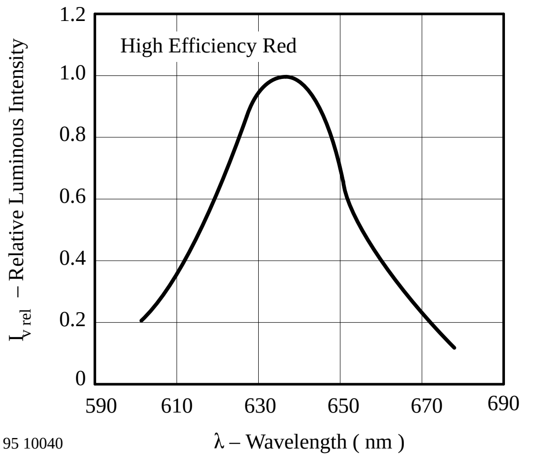


Figure 9. Relative Luminous Intensity vs. Wavelength

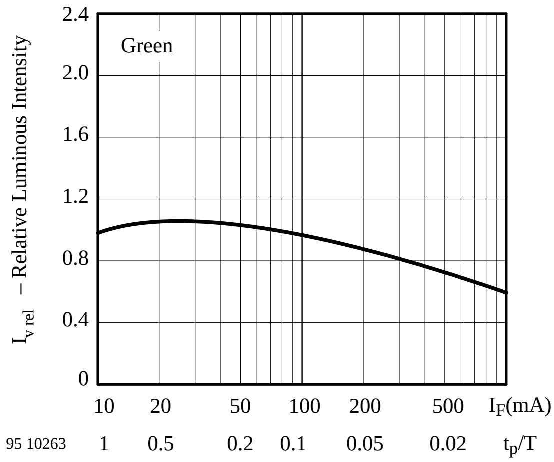


Figure 12. Rel. Lumin. Intensity vs. Forw. Current/Duty Cycle

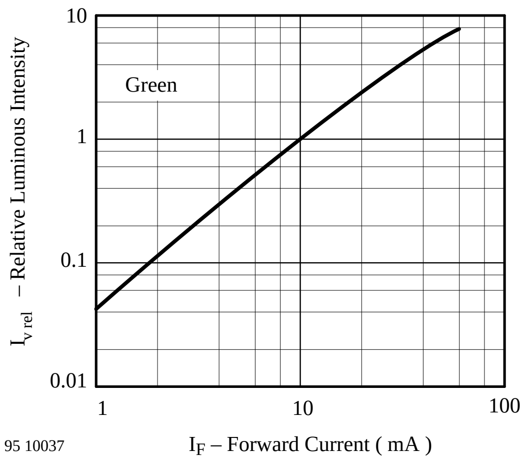


Figure 13. Relative Luminous Intensity vs. Forward Current

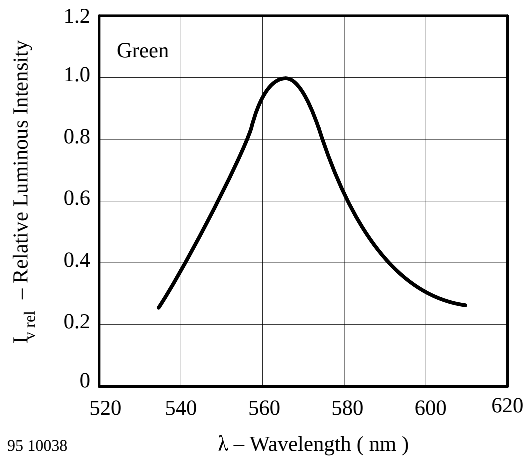
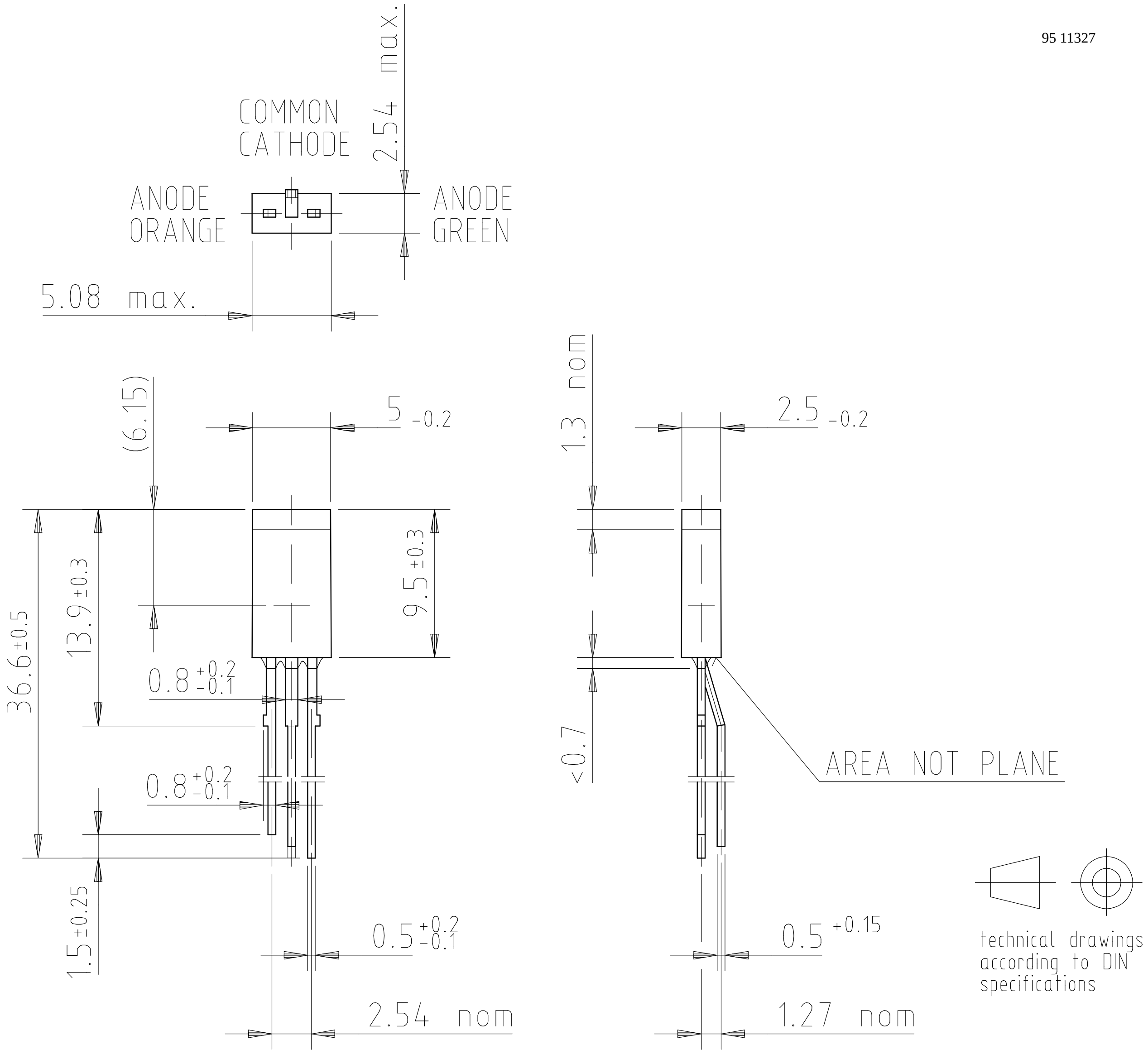


Figure 14. Relative Luminous Intensity vs. Wavelength

Dimensions in mm



Ozone Depleting Substances Policy Statement

It is the policy of **TEMIC TELEFUNKEN microelectronic GmbH** to

1. Meet all present and future national and international statutory requirements.

2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

TEMIC TELEFUNKEN microelectronic GmbH semiconductor division has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively

2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA

3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

TEMIC can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

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